# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

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V <sub>CES</sub>	650V
I <sub>C(100°C)</sub>	30A
V <sub>CE(sat) (Typ.)</sub>	1.5V
P <sub>D</sub>	194W

#### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching & Low Switching Loss
- 3) Short Circuit Withstand Time 2µs
- 4) Pb free Lead Plating ; RoHS Compliant

#### Applications

Solar Inverter

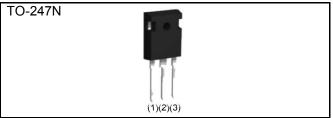
UPS

Welding

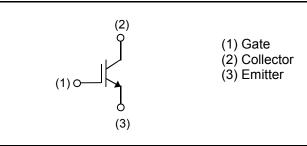
IH

PFC

#### Outline



#### Inner Circuit



#### Packaging Specifications

Туре	Packaging	Tube
	Reel Size (mm)	-
	Tape Width (mm)	-
	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTV60TS65

#### •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

	· -		,	
Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage	V <sub>GES</sub>	±30	V	
Collector Current	$T_{\rm C}$ = 25°C	Ι <sub>C</sub>	60	А
Collector Current	$T_{\rm C}$ = 100°C	Ι <sub>C</sub>	30	А
Pulsed Collector Current	I <sub>CP</sub> *1	120	А	
Power Dissinction	$T_{\rm C}$ = 25°C	P <sub>D</sub>	194	W
Power Dissipation	T <sub>C</sub> = 100°C	P <sub>D</sub>	97	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	–55 to +175	°C

\*1 Pulse width limited by T<sub>imax.</sub>

#### Thermal Resistance

Parameter	Symbol	Values			Unit
Faranielei		Min.	Тур.	Max.	Onit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.77	°C/W

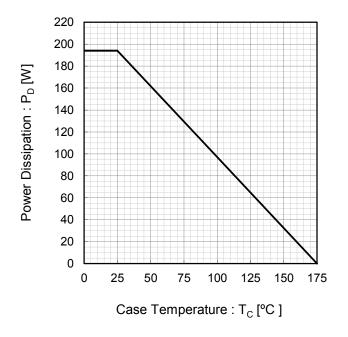
## ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Symbol Conditions		Values		
Faranielei	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	I <sub>C</sub> = 10μΑ, V <sub>GE</sub> = 0V	650	-	-	V
Collector Cut - off Current	I <sub>CES</sub>	V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V	-	-	10	μA
Gate - Emitter Leakage Current	I <sub>GES</sub>	V <sub>GE</sub> = ±30V, V <sub>CE</sub> = 0V	-	-	±200	nA
Gate - Emitter Threshold Voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 21.0mA	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 30A, V <sub>GE</sub> = 15V T <sub>j</sub> = 25°C T <sub>j</sub> = 175°C	-	1.5 1.85	1.9 -	V

# •IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

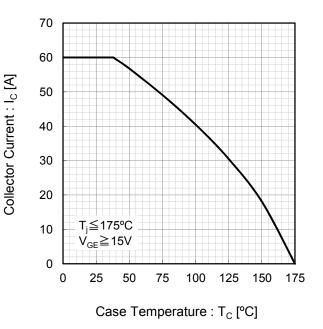
Deremeter	Symbol	Conditions	Values			1.114
Parameter	Symbol	Conditions	Min. Typ.		Max.	Unit
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V	-	1730	-	
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V	-	74	-	pF
Reverse Transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	30	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V	-	64	-	
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 30A	-	14	-	nC
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	24	-	
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 30A, V <sub>CC</sub> = 400V	-	33	-	
Rise Time	t <sub>r</sub>	$V_{GE}$ = 15V, $R_{G}$ = 10 $\Omega$	-	12	-	
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 25°C	-	105	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	40	-	
Turn - on Switching Loss	$E_{on}$	*E <sub>on</sub> includes diode	-	0.57	-	m
Turn - off Switching Loss	$E_{off}$	reverse recovery	-	0.50	-	mJ
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 30A, V <sub>CC</sub> = 400V	-	32	-	
Rise Time	t <sub>r</sub>	$V_{GE}$ = 15V, $R_G$ = 10 $\Omega$	-	13	-	
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 175°C	-	121	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	80	-	
Turn - on Switching Loss	Eon	*E <sub>on</sub> includes diode	-	0.63	-	m
Turn - off Switching Loss	$E_{off}$	reverse recovery	-	0.72	-	mJ
		I <sub>C</sub> = 120A, V <sub>CC</sub> = 520V				
Reverse Bias Safe Operating Area	RBSOA	V <sub>P</sub> = 650V, V <sub>GE</sub> = 15V	FU	-		
		R <sub>G</sub> = 100Ω, T <sub>j</sub> = 175°C				
		$V_{CC} \leq 360V$				
Short Circuit Withstand Time	t <sub>sc</sub>	V <sub>GE</sub> = 15V	2	-	-	μs
		T <sub>j</sub> = 25°C				

#### •Electrical Characteristic Curves



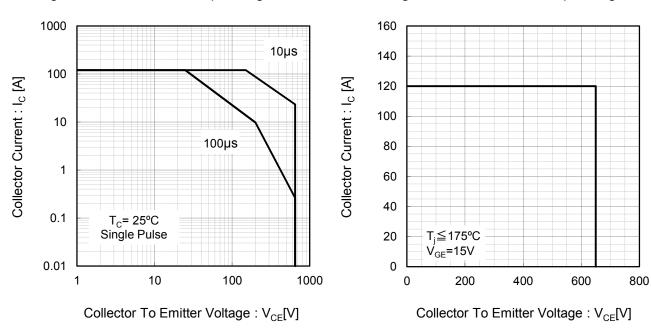
#### Fig.1 Power Dissipation vs. Case Temperature

#### Fig.2 Collector Current vs. Case Temperature

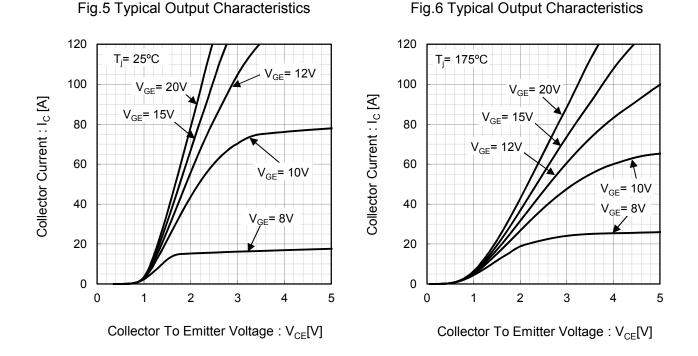


#### Fig.3 Forward Bias Safe Operating Area

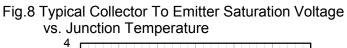
#### Fig.4 Reverse Bias Safe Operating Area

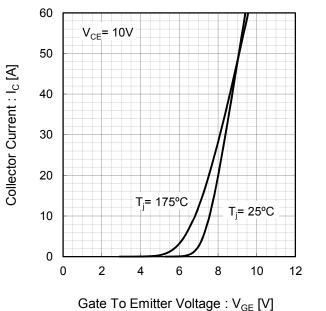


#### Electrical Characteristic Curves

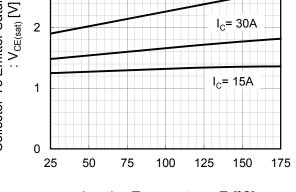


### Fig.7 Typical Transfer Characteristics





V<sub>GE</sub>= 15V Collector To Emitter Saturation Voltage 3 I<sub>C</sub>= 60A I<sub>C</sub>= 30A



Junction Temperature : T<sub>i</sub> [°C]

Fig.10 Typical Collector To Emitter Saturation Voltage

#### •Electrical Characteristic Curves

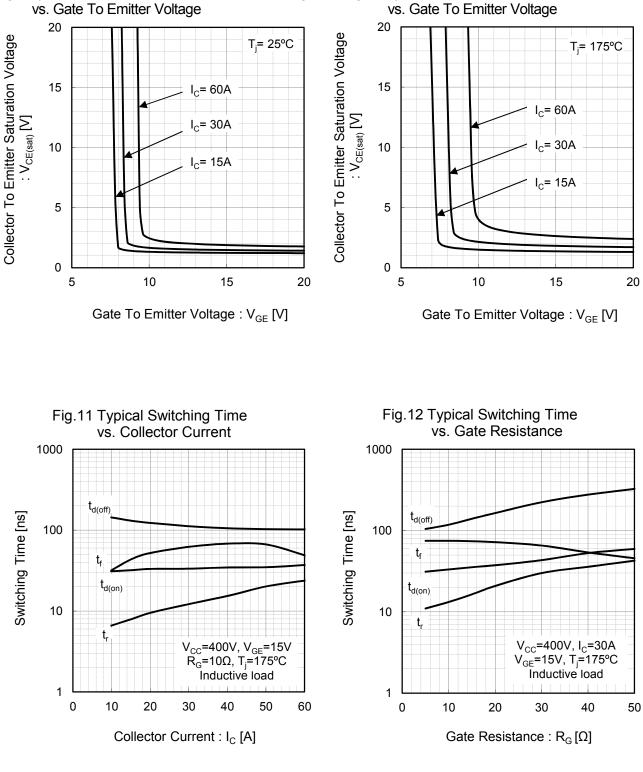
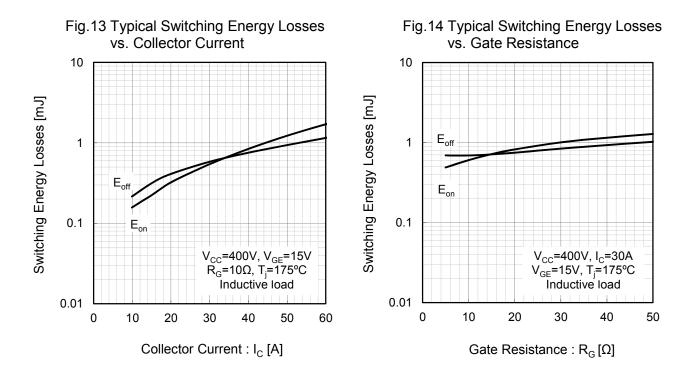


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

#### •Electrical Characteristic Curves



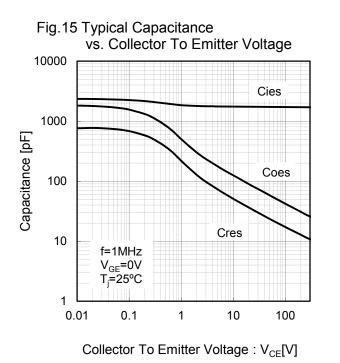
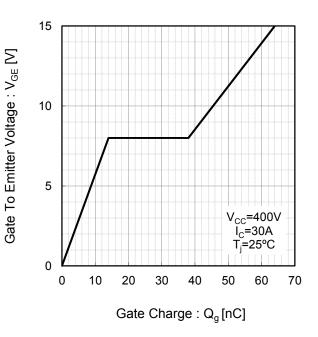


Fig.16 Typical Gate Charge



#### •Electrical Characteristic Curves

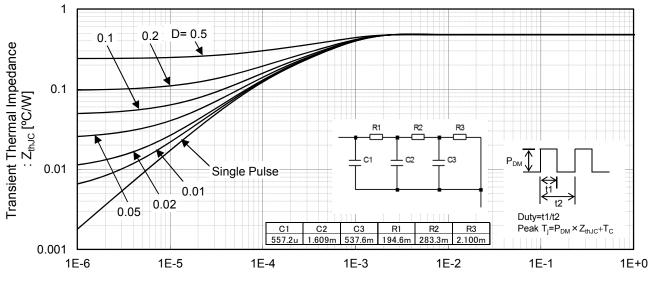
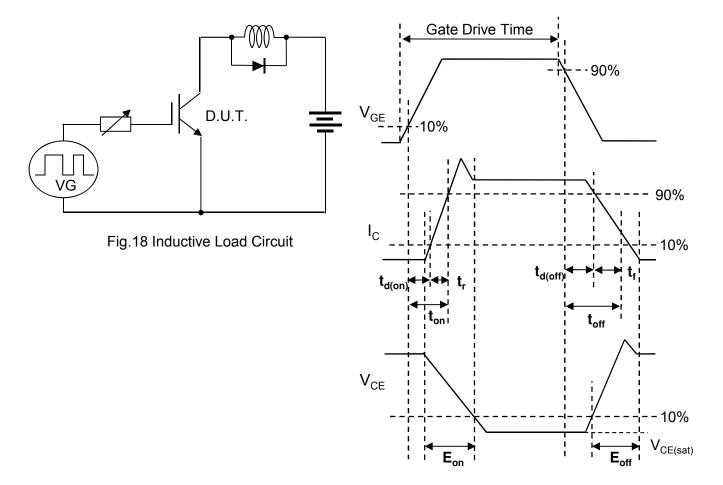


Fig.17 Typical IGBT Transient Thermal Impedance

Pulse Width : t1[s]

#### ●Inductive Load Switching Circuit and Waveform





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# RGTV60TS65 - Web Page

**Distribution Inventory** 

Part Number	RGTV60TS65
Package	TO-247N
Unit Quantity	450
Minimum Package Quantity	30
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes